AMENDMENT UNDER 37 C.F.R. § 1.111

Application No.: 10/561,952

Attorney Docket No.: Q92253

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the

application:

LISTING OF CLAIMS:

(currently amended): A dummy wafer formed by sintering a mixture containing

a silicon carbide powder and a non-metallic sintering auxiliary, wherein

a coating film layer containing silicon carbide is provided on the a surface of the dummy

wafer including at least one of either upper and lower main faces of the dummy wafer by the a

chemical vapor deposition method.

2. (currently amended): The dummy wafer according to claim 1, wherein the

coating film layer containing silicon carbide is provided on the a whole perimeter of the surface

of the dummy wafer including the-a side surface of the dummy wafer.

Claim 3 (canceled).

4. (withdrawn): A method for manufacturing a dummy wafer formed by sintering a

mixture containing a silicon carbide powder and a non-metallic sintering auxiliary, wherein

the method for manufacturing a dummy wafer has a step of providing a coating film layer

containing silicon carbide with a coating film thickness of 20 µm or more and 70 µm or less on

the surface of the dummy wafer including at least one of either upper and lower main faces of the

dummy wafer by the chemical vapor deposition method.

2

AMENDMENT UNDER 37 C.F.R. § 1.111

Application No.: 10/561,952

Attorney Docket No.: Q92253

5. (withdrawn): The method for manufacturing a dummy wafer according to claim 4.

wherein the coating film thickness of the coating film layer is 20 µm or more and 40 µm or less.

6. (withdrawn): The method for manufacturing a dummy wafer according to claim

4 or 5, further having a step of polishing the surface of the coating film layer.

(withdrawn): The method for manufacturing a dummy wafer according to claim

6, wherein the coating film layer after polishing the surface has a thickness of 20 μm or more and

70 µm or less, and a surface roughness (Ra) of 10 nm or less.

Claim 8 (canceled).

7.

3